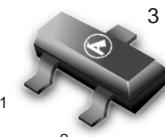


Power MOSFET 200 mAmps, 50 Volts N-Channel SOT-23

Typical applications are dc-dc converters, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low Threshold Voltage ($V_{GS(th)}$: 0.5V...1.5V) makes it ideal for low voltage applications
- Miniature SOT-23 Surface Mount Package saves board space
- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish

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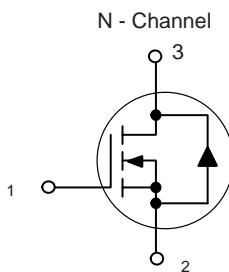


SOT-23 (TO-236AB)

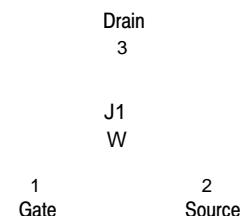
**200 mAmps
50 Volts
 $R_{DS(on)} = 3.5 \Omega$**

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSS}	50	Vdc
Gate-to-Source Voltage – Continuous	V_{GS}	± 20	Vdc
Drain Current – Continuous @ $T_A = 25^\circ\text{C}$ – Pulsed Drain Current ($t_p \leq 10 \mu\text{s}$)	I_D I_{DM}	200 800	mA
Total Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	225	mW
Operating and Storage Temperature Range	T_J, T_{stg}	-55 to 150	°C
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Maximum Lead Temperature for Soldering Purposes, for 10 seconds	T_L	260	°C



MARKING DIAGRAM & PIN ASSIGNMENT



J1 = Device Code
W = Work Week

ORDERING INFORMATION

Device	Package	Shipping
LBSS138LT1	SOT-23	3000 Tape & Reel
LBSS138LT1G	SOT-23	3000 Tape & Reel

LBSS138LT1
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Drain-to-Source Breakdown Voltage ($V_{GS} = 0 \text{ Vdc}$, $I_D = 250 \mu\text{Adc}$)	$V_{(BR)DSS}$	50	—	—	Vdc
Zero Gate Voltage Drain Current ($V_{DS} = 25 \text{ Vdc}$, $V_{GS} = 0 \text{ Vdc}$) ($V_{DS} = 50 \text{ Vdc}$, $V_{GS} = 0 \text{ Vdc}$)	I_{DSS}	— —	— —	0.1 0.5	μAdc
Gate-Source Leakage Current ($V_{GS} = \pm 20 \text{ Vdc}$, $V_{DS} = 0 \text{ Vdc}$)	I_{GSS}	—	—	± 0.1	μAdc

ON CHARACTERISTICS (Note 1.)

Gate-Source Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 1.0 \text{ mAadc}$)	$V_{GS(\text{th})}$	0.5	—	1.5	Vdc
Static Drain-to-Source On-Resistance ($V_{GS} = 2.75 \text{ Vdc}$, $I_D < 200 \text{ mAadc}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$) ($V_{GS} = 5.0 \text{ Vdc}$, $I_D = 200 \text{ mAadc}$)	$r_{DS(\text{on})}$	— —	5.6 —	10 3.5	Ohms
Forward Transconductance ($V_{DS} = 25 \text{ Vdc}$, $I_D = 200 \text{ mAadc}$, $f = 1.0 \text{ kHz}$)	g_{fs}	100	—	—	mmhos

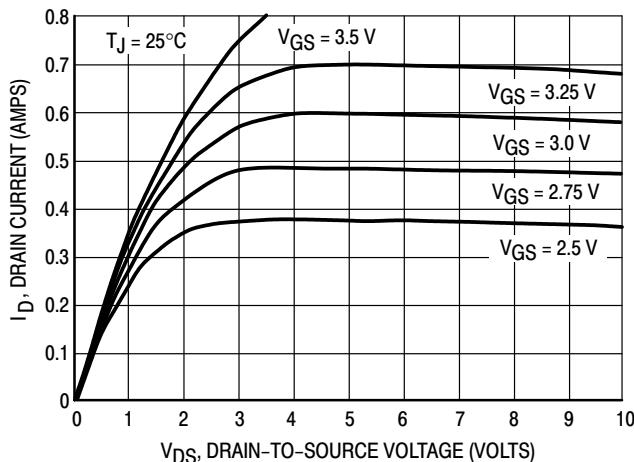
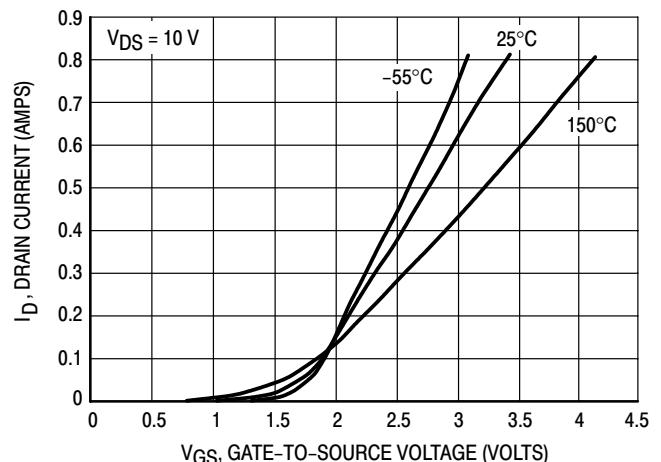
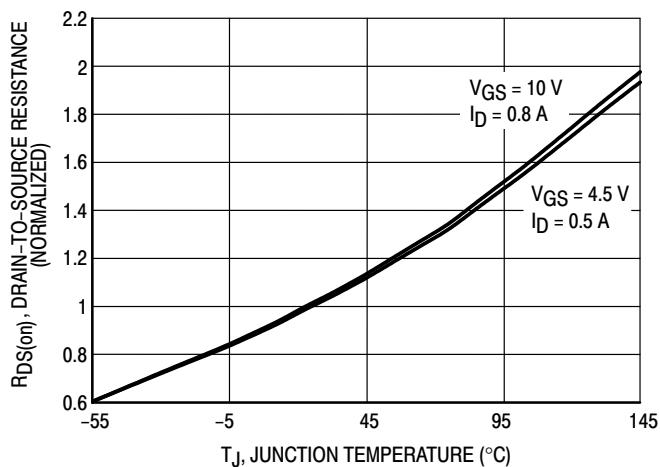
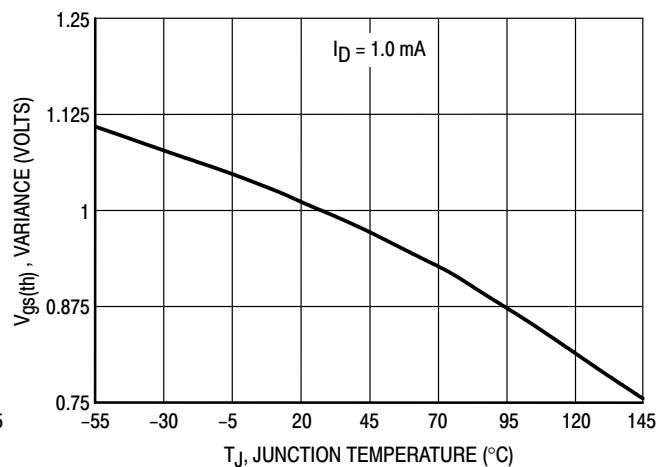
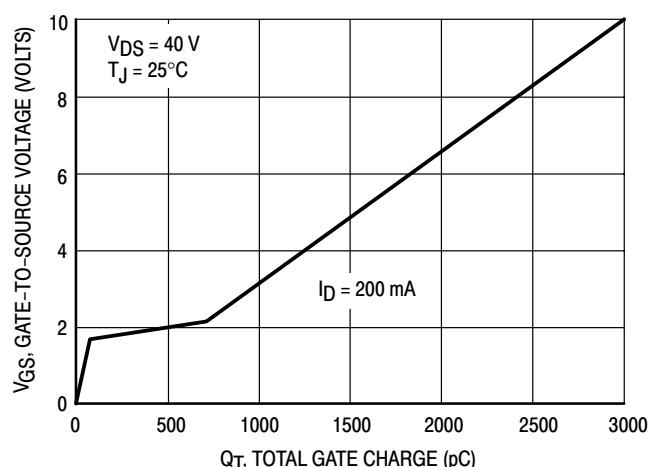
DYNAMIC CHARACTERISTICS

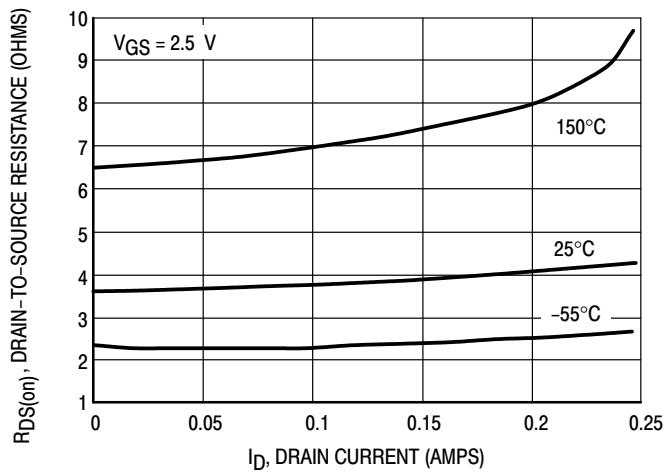
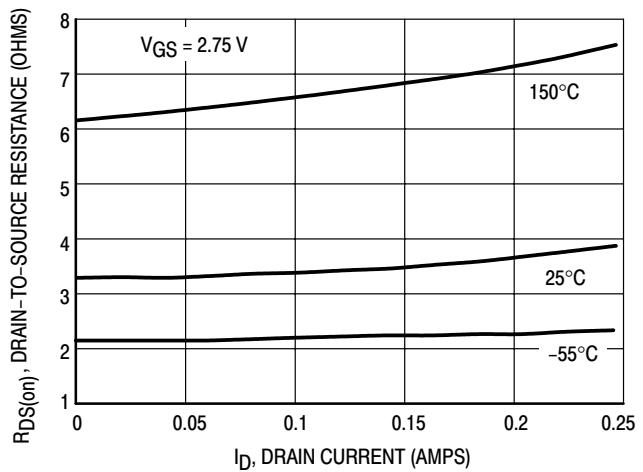
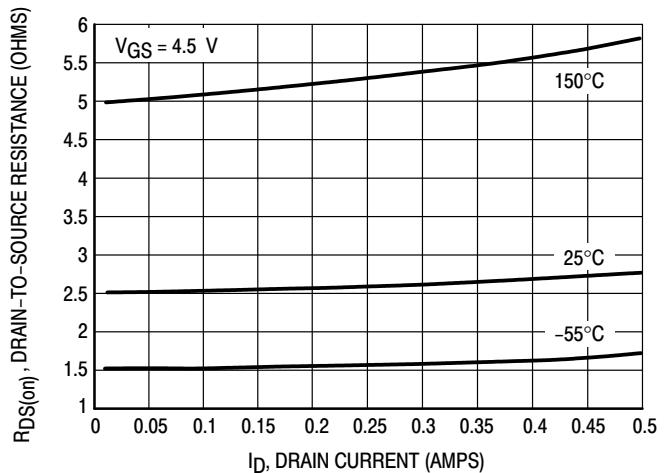
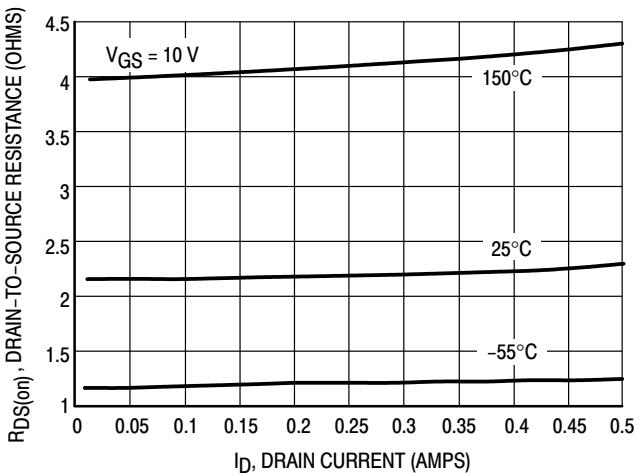
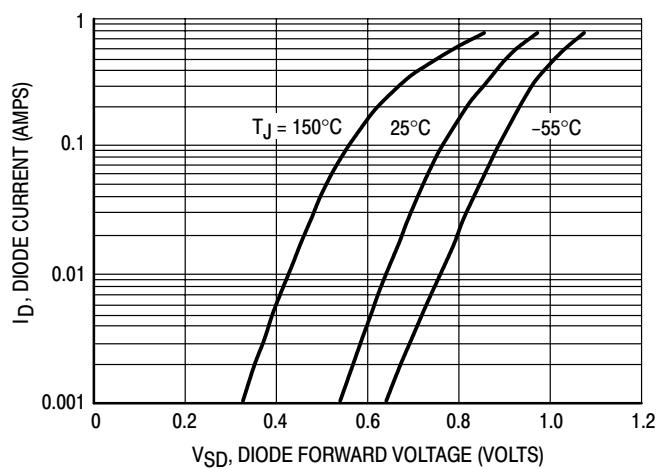
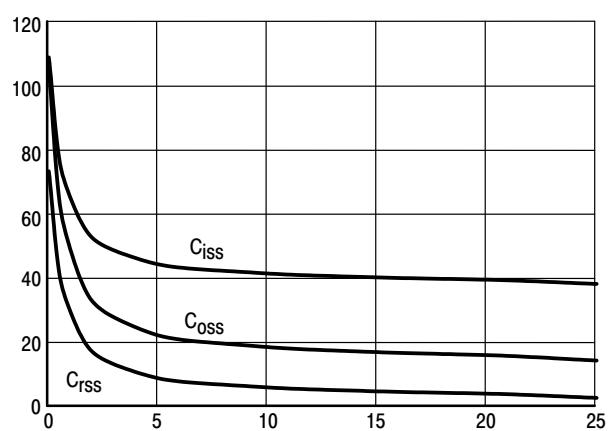
Input Capacitance	($V_{DS} = 25 \text{ Vdc}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$)	C_{iss}	—	40	50	pF
Output Capacitance	($V_{DS} = 25 \text{ Vdc}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$)	C_{oss}	—	12	25	
Transfer Capacitance	($V_{DG} = 25 \text{ Vdc}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$)	C_{rss}	—	3.5	5.0	

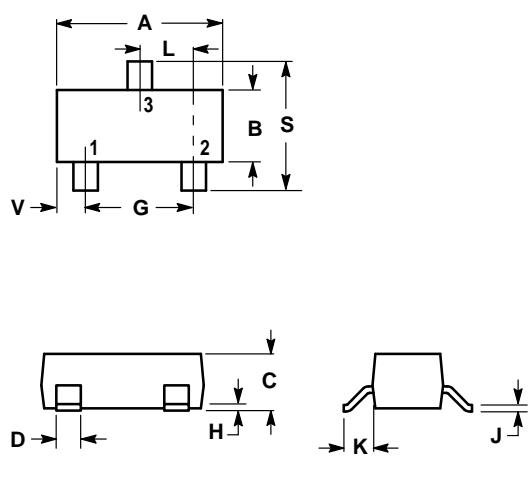
SWITCHING CHARACTERISTICS (Note 2.)

Turn-On Delay Time	$(V_{DD} = 30 \text{ Vdc}$, $I_D = 0.2 \text{ Adc},)$	$t_{d(on)}$	—	—	20	ns
Turn-Off Delay Time		$t_{d(off)}$	—	—	20	

1. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2\%$.
2. Switching characteristics are independent of operating junction temperature.

TYPICAL ELECTRICAL CHARACTERISTICS

Figure 1. On-Region Characteristics

Figure 2. Transfer Characteristics

Figure 3. On-Resistance Variation with Temperature

Figure 4. Threshold Voltage Variation with Temperature

Figure 5. Gate Charge

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TYPICAL ELECTRICAL CHARACTERISTICS

Figure 6. On-Resistance versus Drain Current

Figure 7. On-Resistance versus Drain Current

Figure 8. On-Resistance versus Drain Current

Figure 9. On-Resistance versus Drain Current

Figure 10. Body Diode Forward Voltage

Figure 11. Capacitance

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NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

PIN 1. BASE
2. Emitter
3. Collector

